

THE COMPOSITION LINES OF THE VISIBLE BAND OF SYNTHETIC DIAMOND

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Abstract

The visible band (band A) of Photoluminescence spectra of high-purity synthesized diamond is analyzed by deconvolution technique. A set of eight lines with distinct peak energy are found. The peak energy and the width of these lines were either constant or varies very slightly with temperature. The amplitude of the lines are significantly temperature. The closeness of the temperature that the amplitudes of these lines reach their minimum and the temperature which the Free-exiton emission is maximum at, is an indication of the competition between these two effects.

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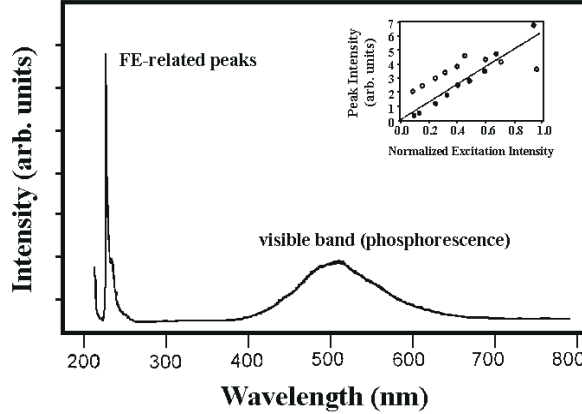


FIG. 1. PL spectra at room temperature, corrected for the measurement sensitivity. The shoulder at 220 nm is due to Rayleigh scattering and Raman peak of diamond. The inset shows the peak intensity dependence on input power; open circle, visible band (at 520 nm); close circle, FE emission (at 235 nm). The line is drawn to guide the eye.[4]

The vacancies and their related properties in diamond and Diamond-Like Carbon (DLC) both in theoretical aspect [1] and experimental results [2] are fascinating subjects. DLC produced by different techniques, artificial diamond produced by high pressure and high temperature show peculiar Photoluminescence (PL) [3,4], Cathodeluminescence (CL) [5] and absorption [2]. There are different peaks and cranks in the absorption, PL and CL spectra of these materials, which some of them are related to the vacancies present in them. Many of these peaks are not simple and are a combination of different absorption or emission lines [2]. Undisturbed vacancies have almost all the rotational symmetry of the main crystal, which for diamond is T_d . The zero phonon line at 1.673eV and the line at 3.145eV which reported by many groups, are associated to undisturbed neutral vacancies (V°) [6] and undisturbed negatively charged vacancies (V^-) [7] respectively. Much work has been done on the effect of uniaxial stress in natural diamond to explain the lines of the general radiation centers band (GR1) that has many peaks from 1.5eV up to 2.8eV. Strong internal stress exist in DLC films [8]. It has been reported that for films there is a strong correlation between PL intensity and stress [9]. In this article, we show that for artificial diamond similar effect is possible due to local stress effect.

The data analyzed here, is for the sample that was grown by high pressure and high temperature-gradient method where nitrogen-getter was added to the solvent. The nitrogen concentration was estimated to be less than 0.1 ppm by infra-red(IR) absorption spectroscopy. The full width at half maximum of diamond Raman peak at 1333 cm^{-1} is 1.6 cm^{-1} and smaller than that of typical natural type IIa diamond, 1.9 cm^{-1} , which indicates a low concentration of defects in the sample. Still the effect of these defects (vacancies surrounding metallic atoms) is small but visible in Photoluminaces spectra.

The PL spectra of this crystal at several temperatures from 400°K down to 8.4°k were measured and reported by K. Horiuchi and his coworkers [4]. The complete spectra at room temperature is shown in Fig. (1). The strong exciton line in the room temperature spectra of

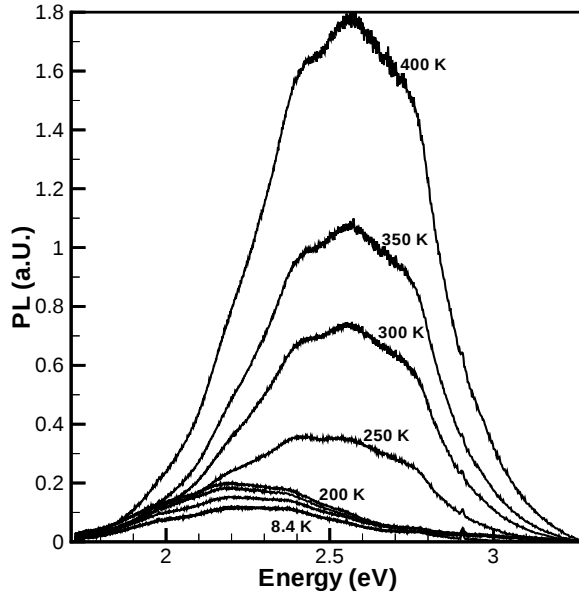


FIG. 2. PL spectra of perfect diamond crystals grown by high pressure and high temperature technique, at different temperatures from 400°K down to 8.4°K.

this crystal is also the evidence of its high quality [4]. At all temperature the PL spectra of this sample has a broad and complicated band from 1.5eV to 3.2eV, which are shown in Fig. (2). In the paper by Horiuchi *et al* was written: "the peaks from 350 nm up to 750 nm (3.5 eV down to 1.65 eV) are the combination of two bands one at 570 nm (2.17 eV) and the second one around 520 nm (2.38 eV)". As it is apparent from the spectra and through our experience, there are more than two lines present in these spectra. We used the deconvolution technique to analyze these reported results.

The spectra obtained at different temperatures were deconvoluted by normalized Gaussians with a greater than 99.95% accuracy for high temperature ones down to 99.5% accuracy for low temperature ones. We used as guide for our deconvolution, the cranks in the spectra and the narrow lines that were nicely apparent at low temperature. All spectra are deconvoluted to eight normalized Gaussian lines. The results for 400°K and 8.4°K are shown in Fig. (3). For other temperatures the results are similar and the pick energy of each line remain constant. At each temperature the widths of all lines are the same and changes slightly as the temperature is lowered. The amplitude of each lines varies significantly with temperature. The deconvolution results are given in table (1).

Fig.(4) shows the temperature dependence of the amplitude of these lines. The amplitude of all the lines decrease as the temperature is lowered and all have minimums at some temperatures in the range of 150 – 200°K. The temperatures that these lines have minimum at, are close to the temperature where the amplitude of Free-exciton (FE) related emission is maximum [4]. These two, emission via FE and emission via vacancies are competing in this temperature region. In addition to the explanation of Horiuchi *etal.* for the existence of a trap, one might

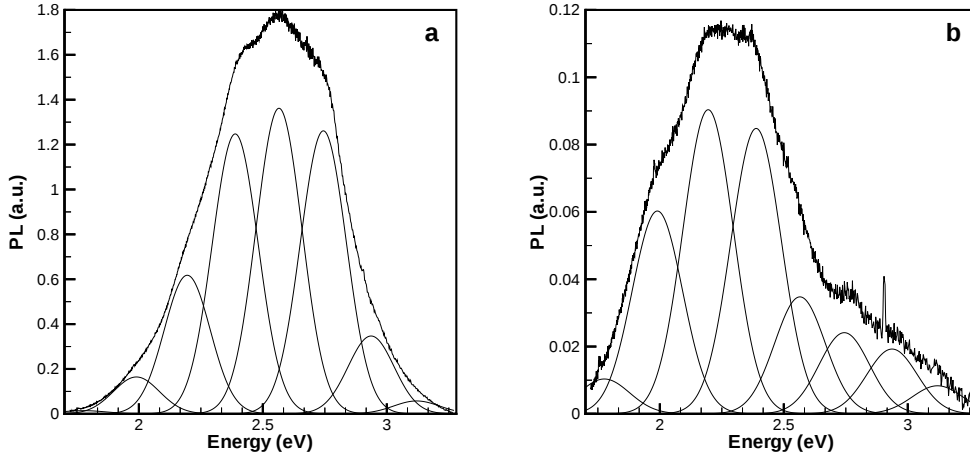


FIG. 3. Deconvoluted Photoluminescence spectra of artificial diamond taken at a) 400°K and b) 8.4°K. At each temperature the width of all Gaussian lines are the same.

say that some of these lines are related to each other and to neutral vacancy V° via Jahn-Teller effect [2]. The ground state of V° is doubly degenerated and close to the top of the valance band [10]. Local strong stress exists in this artificial diamond due to the metallic atoms present in it. Because of this stress, there would be a symmetry braking. The symmetry braking splits the degenerate states and as a consequence the V° ground state will split to two sub-levels, one very close to the top of the valance band and the second above it. The state close to the top of the valance band interferes with (FE) formation. With temperature decrease this interference reduces and the (FE) effect increases. For V^- similar effect could be happened. The large width of these lines are due to the size of the clusters surrounding each metallic atom.

By deconvolution of the Photoluminescence spectra of artificial diamond at different temperatures we found that as it is in the case of DLC films, there exist vacancies under stress in the regions surrounding metallic atoms. In addition to this there might be a competition between Photoluminescence via vacancies and via (FE).

TABLE I. The deconvolution results of Photoluminescence spectra of artificial diamond. First row is the temperature, $T(K)$, where each spectra were taken at. The tenth row is the width, W , of relative peak in $eV \times 10^{-5}$. The last row is the deconvolution accuracy, $Acc.(%)$. The first column is the peak energy, $E(eV)$. The rest in the entire of the table is amplitude in arbitrary unit

$T(K) \rightarrow$	400	350	300	250	200	150	100	50	8.4
$E(eV) \downarrow$									
1.776	187	159	230	306	421	345	227	170	149
1.990	2156	1380	1220	1263	1500	1600	1147	850	867
2.195	8100	4960	3680	2600	2139	2330	1769	1360	1300
2.389	16360	9920	6960	3740	1710	1870	1496	1220	1220
2.565	17860	10810	7420	3460	750	794	661	510	500
2.744	16540	9700	6390	2790	734	454	454	320	347
2.937	4550	2490	1550	600	47	236	292	237	277
3.112	754	352	210	67	40	90	133	85	120
$W(eV)$	1720	1720	1720	1760	2070	2100	2062	2030	2070
$Acc.(%)$	99.956	99.958	99.957	99.93	99.88	99.85	99.77	99.676	99.659

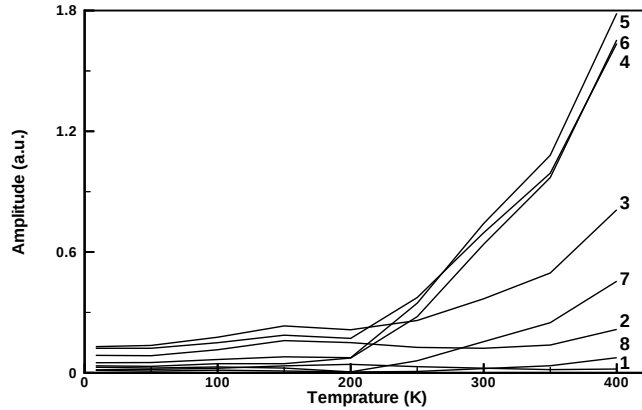


FIG. 4. The temperature dependence of the amplitude of spectra lines

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